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Vishay Semiconductors

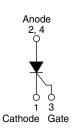
RoHS

COMPLIANT

HALOGEN FREE

Thyristor Surface Mount, Phase Control SCR, 16 A





PRIMARY CHARACTERISTICS							
I _{T(AV)} 16 A							
V _{DRM} /V _{RRM}	1600 V						
V_{TM}	1.25 V						
I _{GT}	45 mA						
TJ	-40 °C to +125 °C						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single SCR						

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- · Renewable energy inverters

DESCRIPTION

The VS-25TTS16SLHM3 of silicon controlled rectifiers is specifically designed for medium power switching and phase control applications.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	3.5	5.5						
Aluminum IMS, R _{thCA} = 15 °C/W	8.5	13.5	A					
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	16.5	25.0						

Note

• T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	16	Δ.						
I _{RMS}		25	Α						
V _{RRM} /V _{DRM}		1600	V						
I _{TSM}		350	Α						
V _T	16 A, T _J = 25 °C	1.25	V						
dV/dt		500	V/µs						
dl/dt		150	A/µs						
TJ		-40 to +125	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} , AT 125 °C mA						
VS-25TTS16SLHM3	1600	1600	10						



ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEG	T CONDITIONS	VAL	UNITS				
PARAMETER	STINIBUL	SYMBOL TEST CONDITIONS		TYP.	UNITS				
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° c	onduction half sine wave	1	6				
Maximum RMS on-state current	I _{RMS}			2	5	Α			
Maximum peak, one-cycle,		10 ms sine pulse, r	ated V _{RRM} applied	30	00	_ ^			
non-repetitive surge current	I _{TSM}	10 ms sine pulse, r	no voltage reapplied	3	50				
Maximum I ² t for fusing	l ² t	10 ms sine pulse, r	ated V _{RRM} applied	450		A 2-			
Maximum i-t for fusing	1-1	10 ms sine pulse, r	630		- A ² s				
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms	s, no voltage reapplied	6300		A²√s			
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.25		V			
On-state slope resistance	r _t	T 105 %C		12.0		mΩ			
Threshold voltage	V _{T(TO)}	$T_{J} = 125 ^{\circ}\text{C}$.0	V				
Maximum various and divest leakens are	1 /1	T _J = 25 °C	V Dated V A/	0	.5				
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	$V_R = Rated V_{RRM}/V_{DRM}$		0				
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		-	150	mA			
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C			00				
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ max., linear to 80 %, $V_{DRM} = R_g - k = Open$			00	V/µs			
Maximum rate of rise of turned-on current	dl/dt	-			150				

TRIGGERING									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum peak gate power	P _{GM}		8.0	W					
Maximum average gate power	P _{G(AV)}		2.0	VV					
Maximum peak positive gate current	+ I _{GM}		1.5	Α					
Maximum peak negative gate voltage	- V _{GM}		10	V					
		Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA					
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	45						
		Anode supply = 6 V, resistive load, T _J = 125 °C	20						
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5						
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	,,					
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V					
Maximum DC gate voltage not to trigger	V_{GD}	T = 105 °C V = Poted value	0.25						
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA					

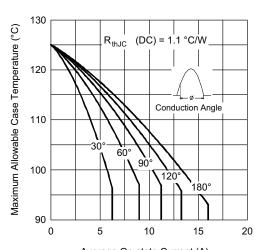
SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9					
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C		μs				
Typical turn-off time	t _q	1j = 125 G	110					



THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C				
Soldering temperature T		For 10 s (1.6 mm from case)	260					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.1	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Marking device		Case style D ² PAK (TO-263AB)	25TTS	316SH				

Note

 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μ m] copper 40 °C/W



Average On-state Current (A)
Fig. 1 - Current Rating Characteristics

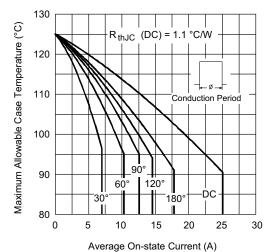


Fig. 2 - Current Rating Characteristics

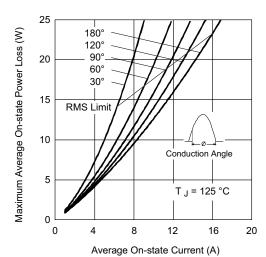


Fig. 3 - On-State Power Loss Characteristics

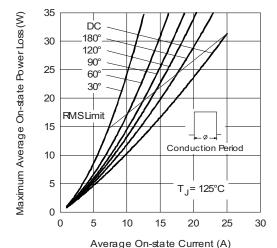
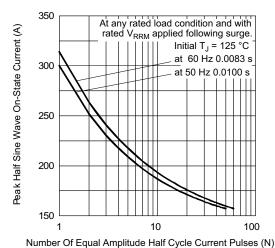


Fig. 4 - On-State Power Loss Characteristics

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Fig. 5 - Maximum Non-Repetitive Surge Current

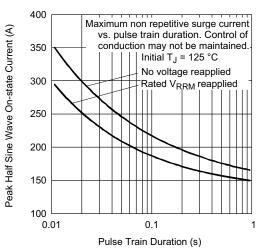


Fig. 6 - Maximum Non-Repetitive Surge Current

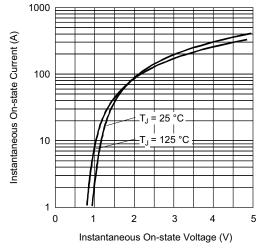
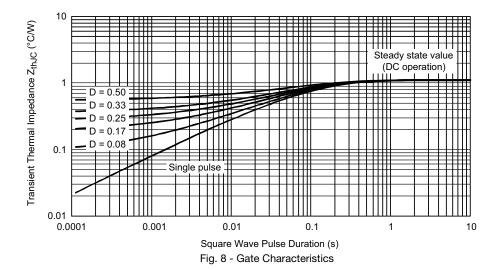


Fig. 7 - On-State Voltage Drop Characteristics



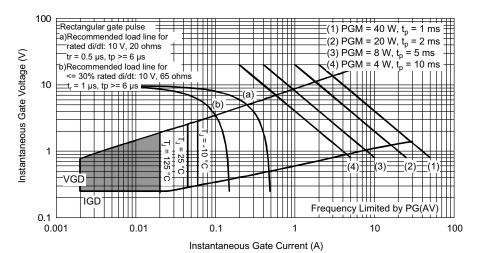
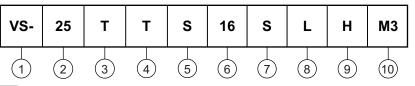


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (25 = 25 A)
- 3 Circuit configuration:
 - T = single thyristor
- 4 Package:
 - $T = D^2PAK (TO-263AB)$
- 5 Type of silicon:
 - S = standard recovery rectifier
- 6 Voltage rating: Voltage code x 100 = V_{RRM} ------ 16 = 1600 V
- 7 S = surface mountable
- L = tape and reel (left oriented), for different orientation, contact factory
- 9 H = AEC-Q101 qualified
- 10 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

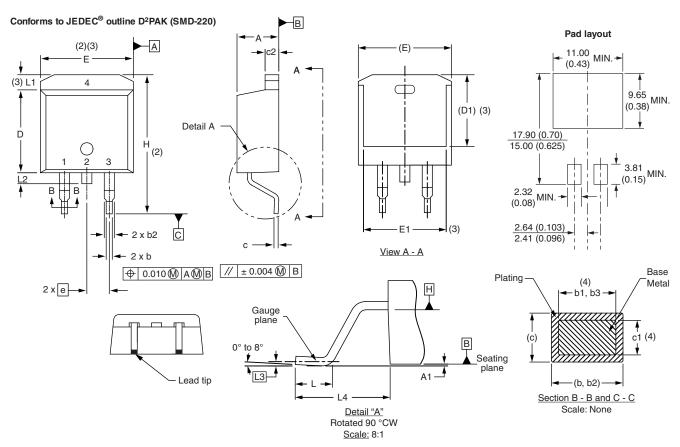
ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-25TTS16SLHM3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96317				



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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